TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

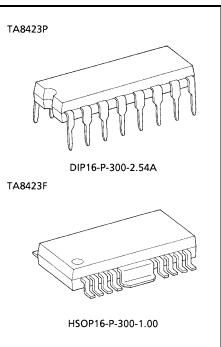
TA8423P,TA8423F

3 PHASE BI-DIRECTIONAL HALL MOTOR DRIVER

The TA8423P, TA8423F are 3 phase Bi–Directional Hall Motor Driver IC designed for VCR (Capstan, head and reel), ADP, Tape Deck, FDD and other Output Driver for 3 phase bipolar Hall motors.

FEATURES

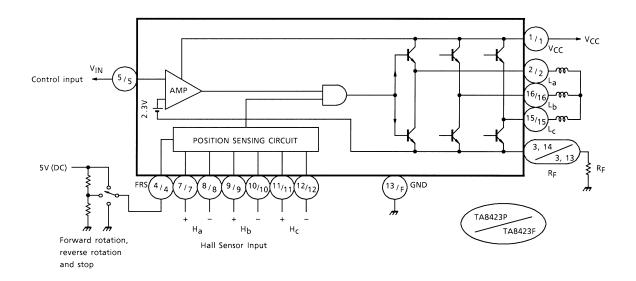
- Few external parts required
- Wide operating supply voltage range : V_{CC} (opr) = 7~17 V
- Forward rotation, reverse rotation and stop are controlled by 1 terminal signal control and easy to interface with CPU.
- High sensitivity of the position sensing circuit. (Hall sensor input) : V_H = 20 mV_p-p (Typ.)
- Large output current : IO (MAX.) = 1.2 A
- Protect diodes equipped for all inputs
- Recommend to use TOSHIBA Ga-As Hall sensor "THS100 series"
- Built-in internal reference
- Built-in thermal shut down circuit



Weight

DIP16-P-300-2.54A : 1.11g (Typ.) HSOP16-P-300-1.00 : 0.50g (Typ.)

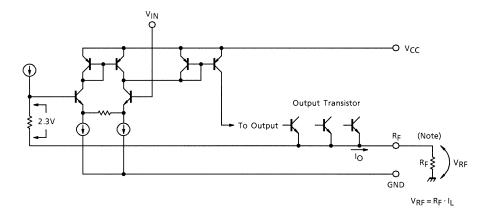
BLOCK DIAGRAM



PIN FUNCTION

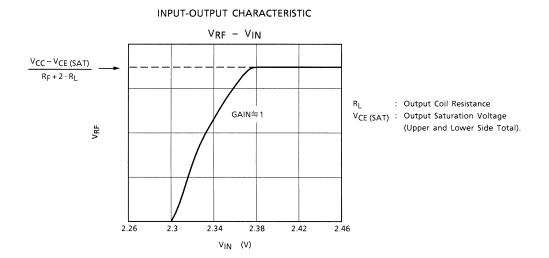
PIN No.		SYMBOL	FUNCTION DESCRIPTION		
Р	F	STMBOL	FUNCTION DESCRIPTION		
1	1	Vcc	Power supply input terminal.		
2	2	La	a-phase drive output terminal.		
3	3	R _F	Output current detection terminal.		
4	4	FRS	Forward / Reverse control terminal.		
5	5	V _{IN}	Control Amp. positive input terminal.		
6	6	N.C	Non Connection.		
7	7	H _a +	a-phase Hall Amp. positive input terminal.		
8	8	H _a -	a-phase Hall Amp. negative input terminal.		
9	9	H _b +	b-phase Hall Amp. positive input terminal.		
10	10	H _b -	b-phase Hall Amp. negative input terminal.		
11	11	H _c +	c-phase Hall Amp. positive input terminal.		
12	12	H _c -	c-phase Hall Amp. negative input terminal.		
13	FIN	GND	GND terminal.		
14	13	R _F	Output current detection terminal.		
15	15	Lc	c-phase drive output terminal.		
16	16	Lb	b-phase drive output terminal.		

1. Control input circuit



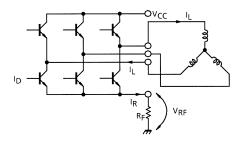
 V_{RF} (= $R_F \cdot I_L$) of feed back voltage is feed backed to negative input of control amp internally. Voltage gain becomes approximately equal to 1 (0dB) by this internal feed back.

Note: 2 terminals (Pin (3), (13) for F version and Pin (3), (14) for P version) are provided for RF terminal to decrease the interference caused by internal common impedance. Both Pins are required to connect for stable operation.



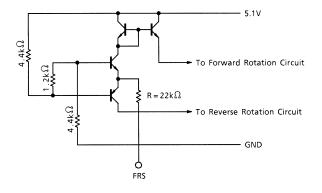
 V_{RF} is feed back voltage generated by RF and output current of I_L , drive current of I_D and internal reference circuit current of $I_R.$ But IO and IR are negligible therefore,

$$\begin{split} &I_{R} << I_{L} + I_{D} \\ &V_{RF} \approx R_{F} \left(I_{L} + I_{O} + I_{R}\right) \\ &I_{L} >> I_{D}, I_{R} \\ &V_{RF} \approx R_{F} \cdot I_{L} \end{split}$$

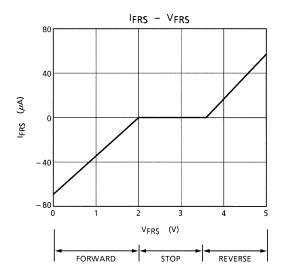


0 Torque state is obtained when less than 2.3 V of control voltage fed into input terminal. 0 Torque state also obtained by select a stop mode by controlling FRS input (Pin (4)). Less supply current is obtained with this condition.

2. FRS CIRCUIT



Forward, Reverse and Stop Modes are selectable by controlling this terminal. Specified voltages are less than 1.3 V (Forward), 2.4 \sim 3.0 V or Open (Stop) and 3.9 V \sim V_{CC} (Reverse). V_{FRS} – I_{FRS} characteristic is shown below.



FUNCTION

	POSITIC	N SENSIN	g input	OUTPUT			
FRS INPUT	Ha	Hb	H _c	La	Lb	L _c	
	1	0	1	Н	L	М	
	1	0	0	Н	М	L	
L	1	1	0	М	Н	L	
L (V ₍₄₎ < 1.3 V)	0	1	0	L	н	М	
	0	1	1	L	М	Н	
	0	0	1	М	L	Н	
	1	0	1	L	Н	М	
	1	0	0	L	М	Н	
н	1	1	0	М	L	Н	
H (3.9 V < V ₍₄₎ < V _{CC})	0	1	0	Н	L	М	
	0	1	1	Н	М	L	
	0	0	1	М	н	L	
	1	0	1				
	1	0	0	High Impedance (Stop)			
М	1	1	0				
(2.4 V < V ₍₄₎ < 3.0 V or Open)	0	1	0				
	0	1	1				
	0	0	1				

Note: "1" of the Hall Sensor input means that voltage above +20 mV is applied to the positive side of each Hall Sensor from the negative side and "0" means that voltage above +20 mV is applied to the negative side from the positive side.

In this case, needless to say, DC potential must be within the specified common mode voltage range of Hall Sensor input.

Further, "H", "M" and "L" of output mean V_{CC} – V_{SAT1} = 1 / 2 V_{CC} and V_{SAT2}, respectively.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTE	ERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage		V _{CC}	18	V	
Output Current		Ι _Ο	1.2	А	
Hall Sensor Input Voltage		V _H	400	mV _{p-p}	
Power Dissipation	TA8423P		1.2 (Note 1)	w	
	TA8423F	PD	0.9 (Note 1)		
			8.3 (Note 2)		
Operating Temperature		Topr	-30~75	°C	
Storage Temperature		T _{stg}	-55~150	°C	

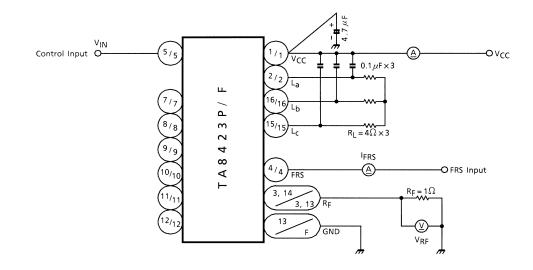
Note 1: No heat sink

Note 2: Tc = 25°C

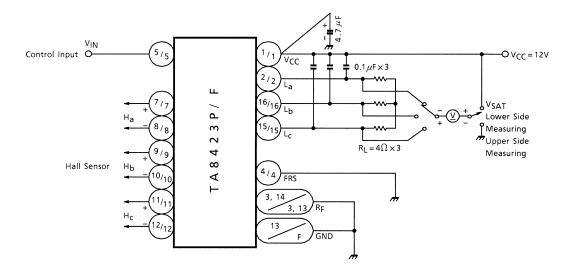
ELECTRICAL CHARACTERISTICS (V_{CC} = 12 V, Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION (TA7262P, TA7262P (LB))	MIN	TYP.	MAX	UNIT		
		I _{CC1}		FRS open	4	8	19			
Supply Current			I _{CC2}	1	FRS = 5 V	4.5	9	21	mA	
		I _{CC3}		V _{CC} = 18 V, FRS = GND	5.5	11	22			
Referen		Voltage	V _{ref}		—	2.2	2.3	2.4	V	
Control Amp.	Voltage Ga	Voltage Gain		1	_	_	0	_	dB	
	Input Curre	Input Current			VIN = 3.5 V	_	2.5	10	μA	
	Reference Ripple Reje	Voltage ection Ratio	R _r		_	-60	_	_	dB	
Cut-off Cur	ront	Upper Side	I _{OL (U)}		V _{CC} = 18 V	_	—	50	μΑ	
	ient	Lower Side	I _{OL (L)}		V _{CC} = 18 V	_	—	50		
Saturation	Upper Side		V _{SAT1}	2	IL = 1 A	_	1.5	1.9	v	
Saturation Voltage		Lower Side	V _{SAT2}		IL = 1 A	_	0.8	1.2	v	
Gain Differe	in Difference		ΔG_V	1	_	_	—	±1	%	
Residual O	utput Voltage		V _{OR}	1	—	— 0 10		mV		
	Input Sens	Input Sensitivity		_	_	_	20	_	mV _{p-p}	
Position Sensing Input	Common Mode Voltage Range		CMR _H	3	_	2.0	_	V _{CC} -3	V	
	Input Offset Voltage		V _{HO}	_	—	_	0	5	mA	
Rotation Control (Input Operation		Forward	V _F	1	—	-0.3	—	1.3	v	
		Stop	VS		_	2.4	—	3.0		
Voltage)		Reverse	V _R]	_	3.9	—	V _{CC}		
Thermal Shut-down Circuit Operating Temperature		TSD	_	—	150	_	_	°C		

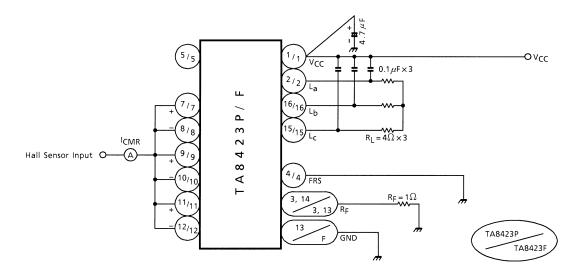
TEST CIRCUIT 1



TEST CIRCUIT 2

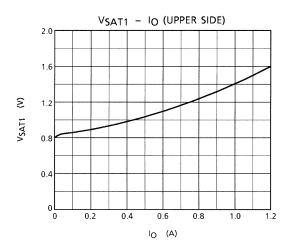


TEST CIRCUIT 3

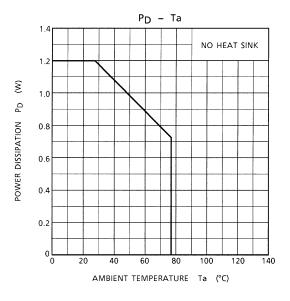


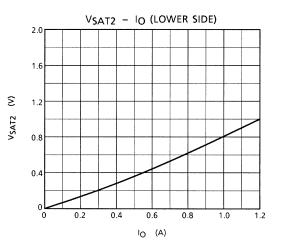
<u>TOSHIBA</u>

Output Amplifier Saturation Voltage Characteristics

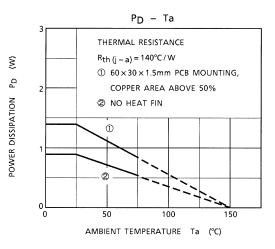




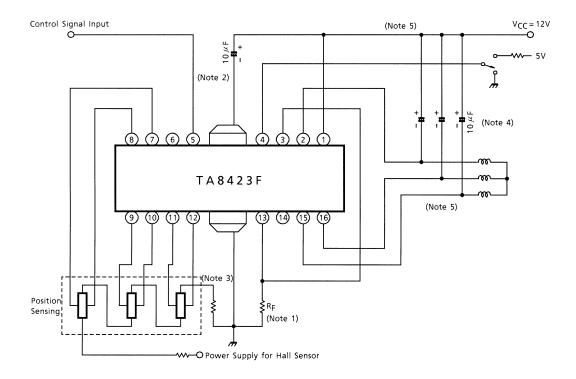




TA8423F



APPLICATION CIRCUIT



- Note 1: Recommendable value of R_F is 0.3 to 5 Ω . It depends on required initial torque, gain, coil impedance and control voltage of Pin 5.
- Note 2: To connect directly to IC Pin (Fin for F version and (13) Pin for P version) and GND to eliminate the influence of common impedance.

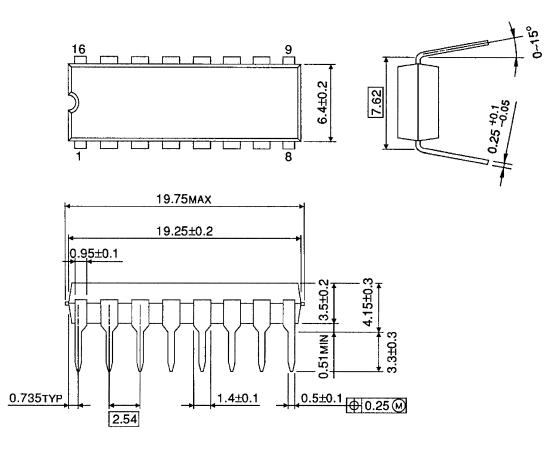
It is required to increase the value of this capacitance for stable operations in case of poor wiring or patterning of PCB.

- Note 3: Special care should be taken not to have a common impedance with GND line, RF GND line and Hall Sensor GND line.
- Note 4: Please select to optimum value for eliminate a vibration noise and parasitic oscillation. And also to change the connection (for example, each output to V_{CC} or to R_F) for getting better characteristics.
- Note 5: Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

PACKAGE DIMENSIONS

DIP16-P-300-2.54A

Unit : mm

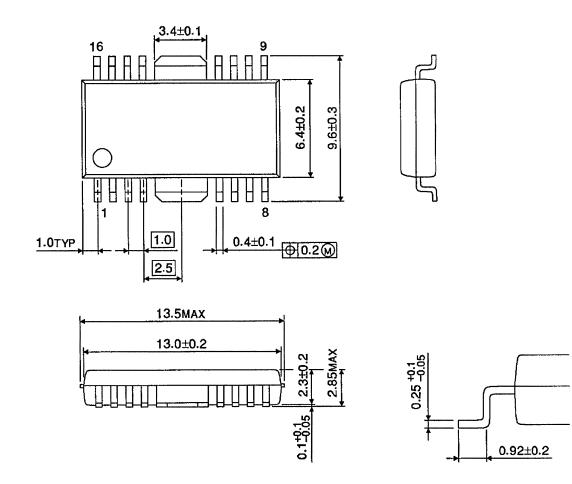


Weight : 1.11 g (Typ.)

PACKAGE DIMENSIONS

HSOP16-P-300-1.00

Unit : mm



Weight: 0.50 g (Typ.)

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